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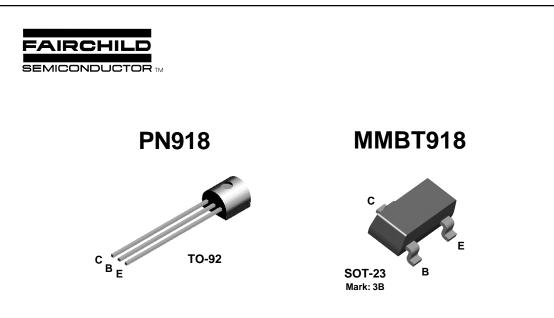


ON Semiconductor®

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NPN RF Transistor

This device is designed for use as RF amplifiers, oscillators and multipliers with collector currents in the 1.0 mA to 30 mA range. Sourced from Process 43.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	15	V
V _{CBO}	Collector-Base Voltage	30	V
V _{EBO}	Emitter-Base Voltage	3.0	V
Ic	Collector Current - Continuous	50	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max U		Units
		PN918	*MMBT918	
P _D	Total Device Dissipation	350	225	mW
	Derate above 25°C	2.8	1.8	mW/∘C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

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NPN RF Transistor

(continued)

Electrical Characteristics	
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Symbol Parameter Test Conditions Min Max Units							
	Symbol	Parameter	Test Conditions	Min	Max	Units	

 $TA = 25^{\circ}C$ unless otherwise noted

OFF CHARACTERISTICS

V _{CEO(sus)}	Collector-Emitter Sustaining Voltage*	$I_{\rm C} = 3.0 \text{ mA}, I_{\rm B} = 0$	15		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 1.0 \ \mu A, \ I_{E} = 0$	30		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	3.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 15 \text{ V}, \text{ I}_{E} = 0$		0.01	μA
		V _{CB} = 15 V, T _A = 150°C		1.0	μA

ON CHARACTERISTICS

h _{FE}	DC Current Gain	I_{C} = 3.0 mA, V_{CE} = 1.0 V	20		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 10$ mA, $I_{\rm B} = 1.0$ mA		0.4	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{\rm C} = 10$ mA, $I_{\rm B} = 1.0$ mA		1.0	V

SMALL SIGNAL CHARACTERISTICS

f _T	Current Gain - Bandwidth Product	$I_{C} = 4.0 \text{ mA}, V_{CE} = 10 \text{ V},$ f = 100 MHz	600		MHz
C _{obo}	Output Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$ $V_{CB} = 0, I_E = 0, f = 1.0 \text{ MHz}$		1.7 3.0	pF pF
C _{ibo}	Input Capacitance	$V_{BE} = 0.5 \text{ V}, I_{C} = 0, f = 1.0 \text{ MHz}$		2.0	pF
NF	Noise Figure	$I_{C} = 1.0 \text{ mA}, V_{CE} = 6.0 \text{ V}, R_{G} = 400\Omega, f = 60 \text{ MHz}$		6.0	dB

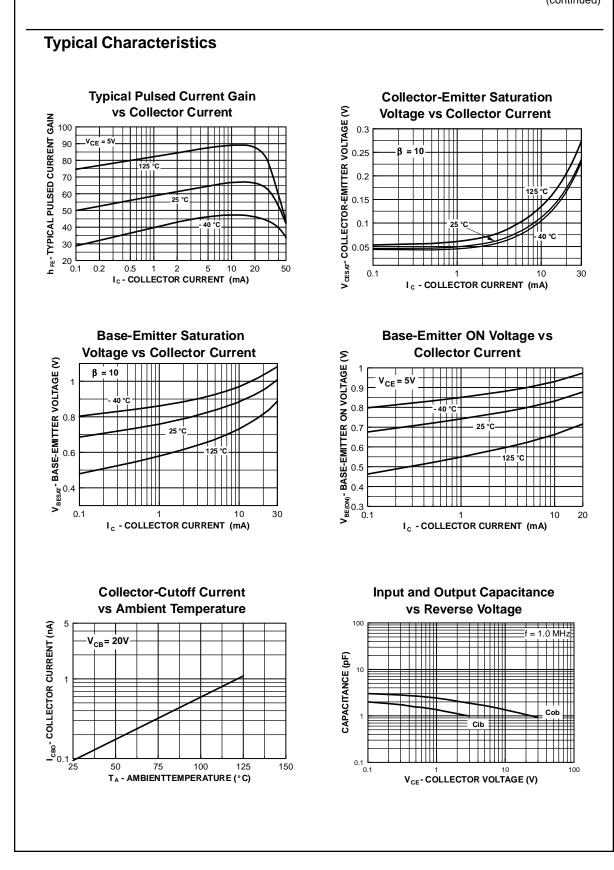
FUNCTIONAL TEST

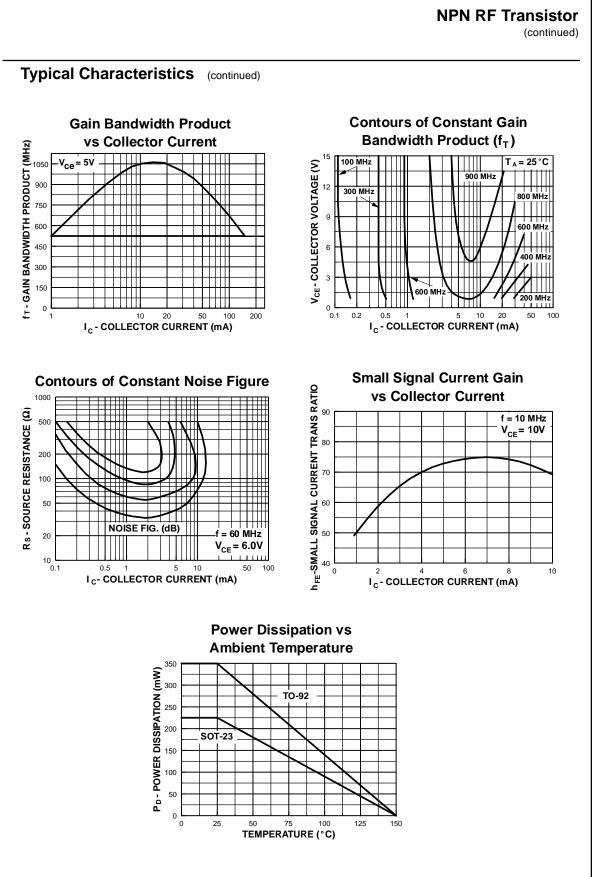
G _{pe}	Amplifier Power Gain	$V_{CB} = 12 \text{ V}, \text{ I}_{C} = 6.0 \text{ mA},$ f = 200 MHz	15	dB
Po	Power Output	$V_{CB} = 15 \text{ V}, I_{C} = 8.0 \text{ mA}, f = 500 \text{ MHz}$	30	mW
η	Collector Efficiency	$V_{CB} = 15 \text{ V}, \text{ I}_{C} = 8.0 \text{ mA},$ f = 500 MHz	25	%

*Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%

NPN RF Transistor (continued)

PN918 / MMBT918

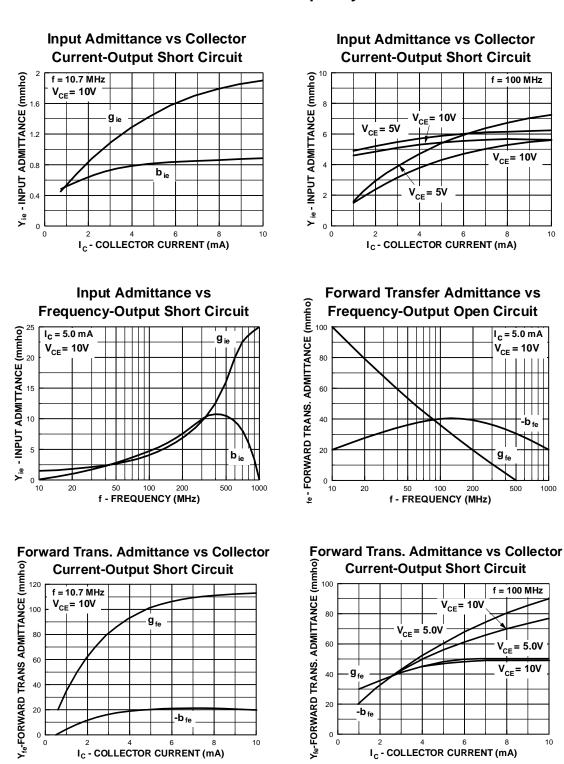




PN918 / MMBT918







PN918 / MMBT918

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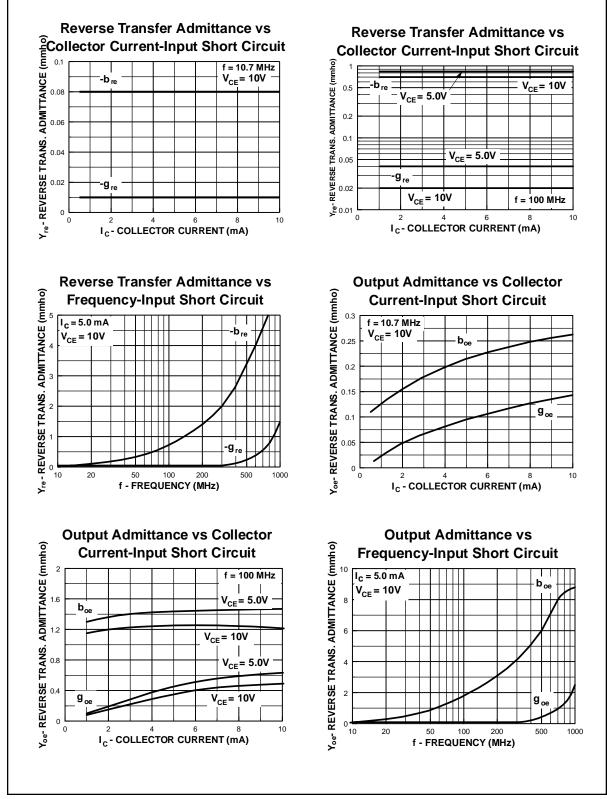
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NPN RF Transistor

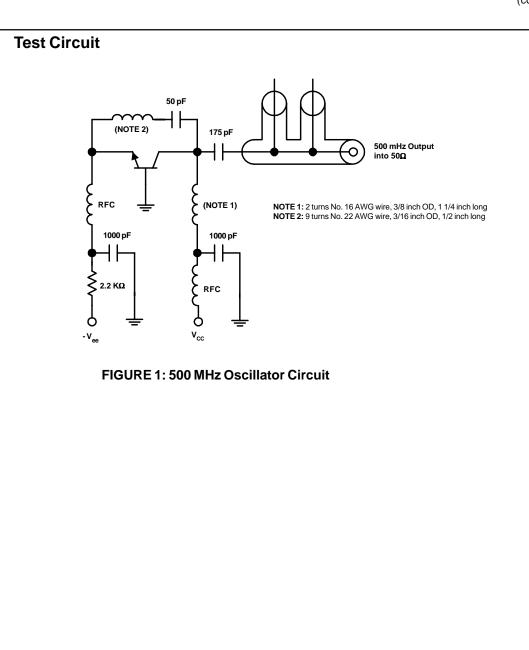
Common Emitter Y Parameters vs. Frequency (continued)



PN918 / MMBT918









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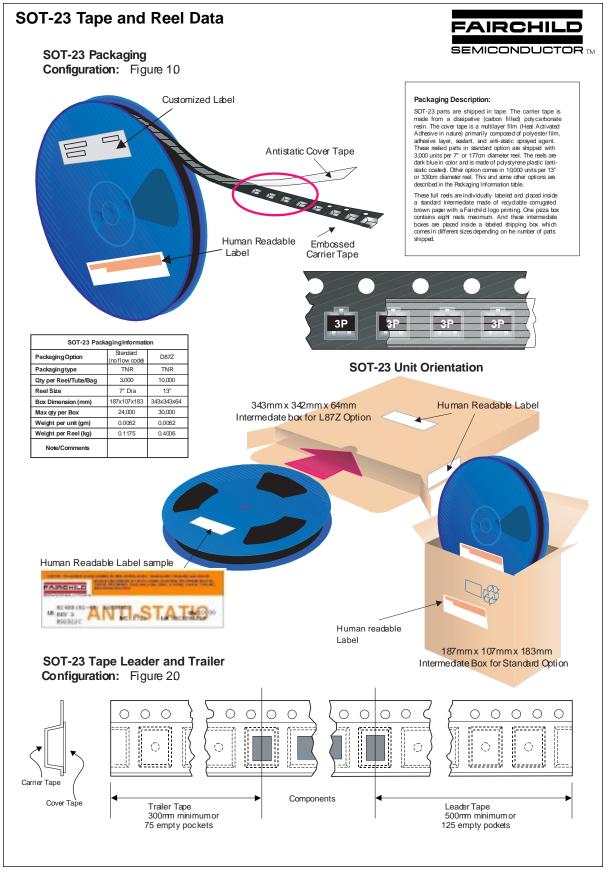
March 2001, Rev. B1





July 1999, Rev. A



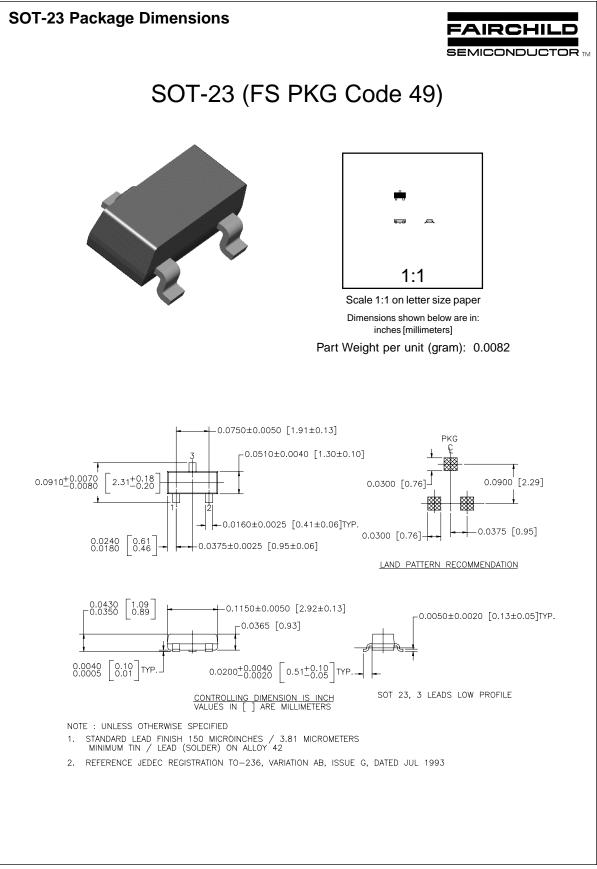


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